PVR100AD-B series

Voltage regulator series Rev. 01 — 31 October 2006

Product data sheet

Product profile

1.1 General description

Integrated Zener diode and NPN bipolar transistor in one package.

Table 1. **Product overview**

Type number	Package	SOT223 complement	
	NXP	JEITA	
PVR100AD-B2V5	SOT457	SC-74	PVR100AZ-B2V5
PVR100AD-B3V0			PVR100AZ-B3V0
PVR100AD-B3V3			PVR100AZ-B3V3
PVR100AD-B5V0			PVR100AZ-B5V0
PVR100AD-B12V	00AD-B12V		PVR100AZ-B12V

1.2 Features

- Integrated Zener diode and bipolar transistor
- Output voltage options: 2.5 V, 3 V, 3.3 V, 5 V and 12 V
- Output power dissipation capability: 380 mW
- Small Surface-Mounted Device (SMD) plastic package

1.3 Applications

Linear voltage regulation

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
NPN transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	45	V
I _C	collector current		-	-	0.1	Α
h _{FE}	DC current gain	$V_{CE} = 1 \text{ V}; I_{C} = 100 \text{ mA}$	160	-	400	



Table 2. Quick reference data ... continued

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Zener di	ode						
Vz	working voltage	$I_Z = 5 \text{ mA}$					
	PVR100AD-B2V5			3.23	3.3	3.37	V
	PVR100AD-B3V0			3.53	3.6	3.67	V
	PVR100AD-B3V3			3.82	3.9	3.98	V
	PVR100AD-B5V0			5.49	5.6	5.71	V
	PVR100AD-B12V			12.7	13	13.3	V
Voltage i	regulator						
Vo	output voltage	I _O = 10 mA	[1]				
	PVR100AD-B2V5	$V_I = 4.5 \text{ V}; I_{ctrl} = 3.5 \text{ mA}$		2.25	2.5	2.75	V
	PVR100AD-B3V0	$V_{I} = 5 \text{ V}; I_{ctrl} = 6.5 \text{ mA}$		2.7	3	3.3	V
	PVR100AD-B3V3	$V_I = 5.3 \text{ V}; I_{ctrl} = 6.5 \text{ mA}$		3.07	3.3	3.53	V
	PVR100AD-B5V0	$V_{I} = 7 \text{ V}; I_{ctrl} = 10 \text{ mA}$		4.65	5	5.35	V
	PVR100AD-B12V	$V_{I} = 14 \text{ V}; I_{ctrI} = 5 \text{ mA}$		11.4	12.3	13.2	V
Line reg	ulation						
$\Delta V_{O}/V_{O}$	relative output voltage variation	I _O = 10 mA	<u>[1]</u>				
	PVR100AD-B2V5	$4.5 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V}; \text{I}_{\text{ctrl}} = 3.5 \text{ mA}$		-10	-	+10	%
	PVR100AD-B3V0	5 V \leq V _I \leq 40 V; I _{ctrl} = 6.5 mA		-10	-	+10	%
	PVR100AD-B3V3	$5.3 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V}; \text{ I}_{\text{ctrl}} = 6.5 \text{ mA}$		-7	-	+7	%
	PVR100AD-B5V0	7 V \leq V _I \leq 40 V; I _{ctrl} = 10 mA		-7	-	+7	%
	PVR100AD-B12V	14 V \leq V _I \leq 40 V; I _{ctrl} = 5 mA		-7	-	+7	%
Load reg	julation						
$\Delta V_{O}/V_{O}$	relative output voltage variation	$5 \text{ mA} \le I_O \le 100 \text{ mA}$	[1]				
	PVR100AD-B2V5	$V_I = 4.5 \text{ V}; I_{ctrl} = 3.5 \text{ mA}$		-10	-	+10	%
	PVR100AD-B3V0	$V_{I} = 5 \text{ V}; I_{ctrl} = 6.5 \text{ mA}$		-10	-	+10	%
	PVR100AD-B3V3	$V_1 = 5.3 \text{ V}; I_{ctrl} = 6.5 \text{ mA}$		-7	-	+7	%
	PVR100AD-B5V0	$V_{I} = 7 \text{ V}; I_{ctrl} = 10 \text{ mA}$		-7	-	+7	%
	PVR100AD-B12V	$V_{I} = 14 \text{ V}; I_{ctrl} = 5 \text{ mA}$		-7	-	+7	%

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

2. Pinning information

Table 3. Pinning

		9		
Pin	Symbol	Description	Simplified outline	Symbol
1	GND	ground		
2	n.c.	not connected	6 5 4	6 5 4
3	VO	output voltage	0	
4	VI	input voltage	1 2 3	TR1
5	VI	input voltage		本 D1
6	REXT	base		1 2 3 006aaa694

3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PVR100AD-B2V5	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				
PVR100AD-B3V0							
PVR100AD-B3V3							
PVR100AD-B5V0							
PVR100AD-B12V							

4. Marking

Table 5. Marking codes

Type number	Marking code
PVR100AD-B2V5	T1
PVR100AD-B3V0	T2
PVR100AD-B3V3	T3
PVR100AD-B5V0	T4
PVR100AD-B12V	T5

5. Limiting values

Table 6. Limiting values

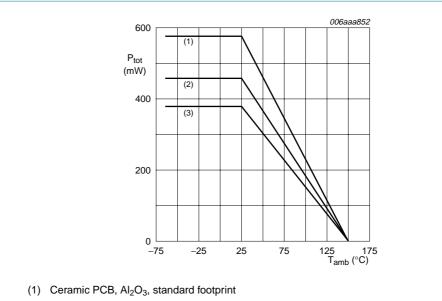
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
NPN tran	nsistor				
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	0.1	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	0.2	Α
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	0.2	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	<u>[1]</u> _	300	mW
			[2] _	380	mW
			[3]	480	mW
Zener di	ode				
l _F	forward current		-	200	mA
I _{ZSM}	non-repetitive peak reverse	$V_Z < 6 V$	-	6	Α
	current	V _Z = 13 V	-	2.5	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	140	mW
Voltage	regulator				
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	380	mW
			[2] _	460	mW
			<u>[3]</u> _	580	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
NPN transistor								
R _{th(j-a)}	thermal resistance from	in free air	[1] _	-	417	K/W		
	junction to ambient		[2] _	-	329	K/W		
			[3] _	-	260	K/W		
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	125	K/W		
Zener dic	ode							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	893	K/W		
Voltage r	egulator							
R _{th(j-a)}	thermal resistance from	in free air	<u>[1]</u> _	-	329	K/W		
	junction to ambient		[2] _	-	272	K/W		
			[3]	-	216	K/W		

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
NPN transistor						
I _{CBO}	collector-base cut-off	$V_{CB} = 20 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
	current	$V_{CB} = 20 \text{ V};$ $I_E = 0 \text{ A}; T_j = 150 \text{ °C}$	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 1 V;$ $I_{C} = 100 \text{ mA}$	160	-	400	
V_{BE}	base-emitter voltage	$V_{CE} = 1 V;$ $I_{C} = 10 \text{ mA}$	-	0.72	-	V
Zener diode						
V_{F}	forward voltage	$I_F = 10 \text{ mA}$	-	-	0.9	V
I_R	reverse current					
	PVR100AD-B2V5	$V_R = 1 V$	-	-	5	μΑ
	PVR100AD-B3V0	V _R = 1 V	-	-	5	μΑ
	PVR100AD-B3V3	V _R = 1 V	-	-	3	μΑ
	PVR100AD-B5V0	V _R = 2 V	-	-	1	μΑ
	PVR100AD-B12V	V _R = 8 V	-	-	0.1	μΑ
V_Z	working voltage	$I_Z = 5 \text{ mA}$				
	PVR100AD-B2V5		3.23	3.3	3.37	V
	PVR100AD-B3V0		3.53	3.6	3.67	V
	PVR100AD-B3V3		3.82	3.9	3.98	V
	PVR100AD-B5V0		5.49	5.6	5.71	V
	PVR100AD-B12V		12.7	13	13.3	V
r _{dif}	differential resistance	$I_Z = 1 \text{ mA}$				
	PVR100AD-B2V5		-	350	600	Ω
	PVR100AD-B3V0		-	375	600	Ω
	PVR100AD-B3V3		-	400	600	Ω
	PVR100AD-B5V0		-	80	400	Ω
	PVR100AD-B12V		-	50	170	Ω
r _{dif}	differential resistance	$I_Z = 5 \text{ mA}$				
	PVR100AD-B2V5		-	85	95	Ω
	PVR100AD-B3V0		-	85	90	Ω
	PVR100AD-B3V3		-	85	90	Ω
	PVR100AD-B5V0		-	15	40	Ω
	PVR100AD-B12V		-	10	30	Ω

PVR100AD-B_SER_1 © NXP B.V. 2006. All rights reserved.

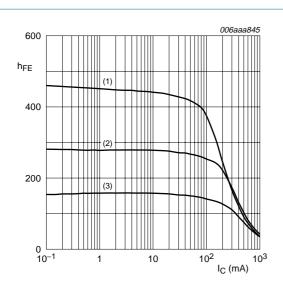
Table 8. Characteristics ... continued $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
S _Z	temperature coefficient	$I_Z = 5 \text{ mA}$					
	PVR100AD-B2V5			-3.5	-2.4	0	mV/K
	PVR100AD-B3V0			-3.5	-2.4	0	mV/K
	PVR100AD-B3V3			-3.5	-2.5	0	mV/K
	PVR100AD-B5V0			-2	1.2	2.5	mV/K
	PVR100AD-B12V			7	9.4	11	mV/K
Voltage regulator	or						
Vo	output voltage	$I_O = 10 \text{ mA}$	<u>[1]</u>				
	PVR100AD-B2V5	$V_{I} = 4.5 \text{ V};$ $I_{ctrI} = 3.5 \text{ mA}$		2.25	2.5	2.75	V
	PVR100AD-B3V0	$V_I = 5 V;$ $I_{ctrl} = 6.5 \text{ mA}$		2.7	3	3.3	V
	PVR100AD-B3V3	$V_I = 5.3 \text{ V};$ $I_{ctrl} = 6.5 \text{ mA}$		3.07	3.3	3.53	V
	PVR100AD-B5V0	$V_I = 7 V;$ $I_{ctrl} = 10 \text{ mA}$		4.65	5	5.35	V
	PVR100AD-B12V	$V_I = 14 \text{ V};$ $I_{ctrl} = 5 \text{ mA}$		11.4	12.3	13.2	V
$\Delta V_O / (V_O \times \Delta T_{amb})$	relative output voltage variation over ambient temperature	I_O = 100 mA; T_{amb} = -55 °C to 150 °C	<u>[1]</u>				
	PVR100AD-B2V5	V _I = 4.5 V		-	38	-	10 ⁻⁶ /K
	PVR100AD-B3V0	V _I = 5 V		-	-78	-	10 ⁻⁶ /K
	PVR100AD-B3V3	$V_{I} = 5.3 \text{ V}$		-	-61	-	10 ⁻⁶ /K
	PVR100AD-B5V0	$V_I = 7 V$		-	634	-	10 ⁻⁶ /K
	PVR100AD-B12V	V _I = 14 V		-	892	-	10 ⁻⁶ /K
Line regulation							
$\Delta V_{O}/V_{O}$	relative output voltage variation	I _O = 10 mA	[1]				
	PVR100AD-B2V5	$4.5 \text{ V} \leq \text{V}_{\text{I}} \leq 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 3.5 \text{ mA}$		-10	-	+10	%
	PVR100AD-B3V0	$5 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 6.5 \text{ mA}$		-10	-	+10	%
	PVR100AD-B3V3	$5.3 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 6.5 \text{ mA}$		-7	-	+7	%
	PVR100AD-B5V0	$7 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 10 \text{ mA}$		-7	-	+7	%
	PVR100AD-B12V	$14 \text{ V} \leq \text{V}_{\text{I}} \leq 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 5 \text{ mA}$		-7	-	+7	%

Table 8. Characteristics ... continued $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

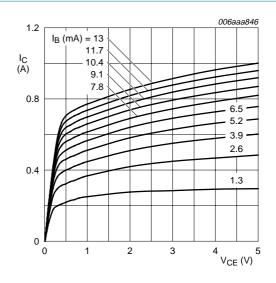
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\Delta V_{O}/(V_{O} \times \Delta V_{I})$	relative output voltage variation over input voltage	I _O = 10 mA	<u>[1]</u>			
	PVR100AD-B2V5	$4.5 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 3.5 \text{ mA}$	-	100	-	10 ⁻⁶ /V
	PVR100AD-B3V0	$5 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 6.5 \text{ mA}$	-	80	-	10 ⁻⁶ /V
	PVR100AD-B3V3	$5.3 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 6.5 \text{ mA}$	-	70	-	10 ⁻⁶ /V
	PVR100AD-B5V0	$7 \text{ V} \le \text{V}_{\text{I}} \le 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 10 \text{ mA}$	-	40	-	10 ⁻⁶ /V
	PVR100AD-B12V	$14 \text{ V} \leq \text{V}_{\text{I}} \leq 40 \text{ V};$ $\text{I}_{\text{ctrl}} = 5 \text{ mA}$	-	20	-	10 ⁻⁶ /V
Load regulation	n					
$\Delta V_{O}/V_{O}$	relative output voltage variation	$5 \text{ mA} \le I_0 \le 100 \text{ mA}$	<u>[1]</u>			
	PVR100AD-B2V5	$V_{I} = 4.5 \text{ V};$ $I_{ctrl} = 3.5 \text{ mA}$	-10	-	+10	%
	PVR100AD-B3V0	$V_I = 5 V;$ $I_{ctrl} = 6.5 \text{ mA}$	-10	-	+10	%
	PVR100AD-B3V3	$V_{I} = 5.3 \text{ V};$ $I_{ctrl} = 6.5 \text{ mA}$	-7	-	+7	%
	PVR100AD-B5V0	$V_I = 7 V;$ $I_{ctrl} = 10 \text{ mA}$	-7	-	+7	%
	PVR100AD-B12V	$V_I = 14 \text{ V};$ $I_{ctrl} = 5 \text{ mA}$	-7	-	+7	%
$\Delta V_{O}/(V_{O} \times \Delta I_{O})$	relative output voltage variation over output current	5 mA ≤ I _O ≤ 100 mA	[1]			
	PVR100AD-B2V5	$V_{I} = 4.5 \text{ V};$ $I_{ctrl} = 3.5 \text{ mA}$	-	-840	-	10 ⁻⁶ /m/
	PVR100AD-B3V0	$V_I = 5 V;$ $I_{ctrl} = 6.5 \text{ mA}$	-	-630	-	10 ⁻⁶ /m/
	PVR100AD-B3V3	$V_{I} = 5.3 \text{ V};$ $I_{ctrl} = 6.5 \text{ mA}$	-	-540	-	10 ⁻⁶ /m/
	PVR100AD-B5V0	$V_I = 7 V;$ $I_{ctrl} = 10 \text{ mA}$	-	-320	-	10 ⁻⁶ /m/
	PVR100AD-B12V	V _I = 14 V; I _{ctrl} = 5 mA	-	-130	-	10 ⁻⁶ /m/

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$.



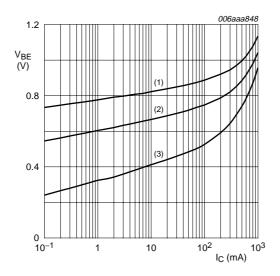
- $V_{CE} = 1 V$
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 2. NPN transistor: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig 3. NPN transistor: Collector current as a function of collector-emitter voltage; typical values



 $V_{CE} = 1 V$

- (1) $T_{amb} = -55 \,^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 4. NPN transistor: Base-emitter voltage as a function of collector current; typical values

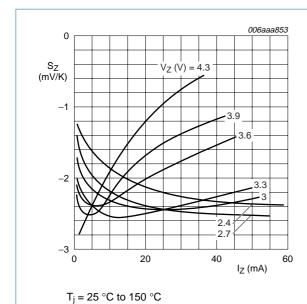


Fig 5. Zener diode: Temperature coefficient as a function of working current; typical values

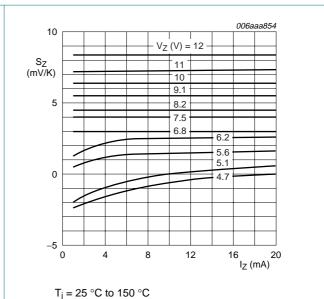
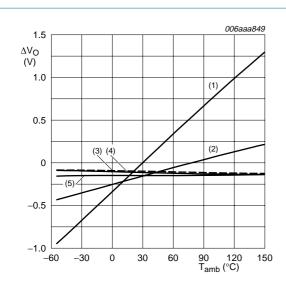


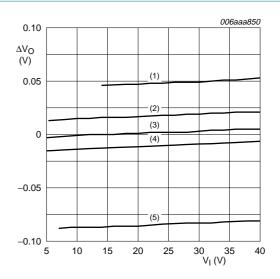
Fig 6. Zener diode: Temperature coefficient as a function of working current; typical values



$$\begin{split} V_I &= V_{O(typ)} + 2 \text{ V; } I_O = 100 \text{ mA;} \\ T_{amb} &= -55 \text{ }^{\circ}\text{C to } 150 \text{ }^{\circ}\text{C} \end{split}$$

- (1) PVR100AD-B12V
- (2) PVR100AD-B5V0
- (3) PVR100AD-B3V3
- (4) PVR100AD-B3V0
- (5) PVR100AD-B2V5

Fig 7. Voltage regulator: Output voltage variation as a function of ambient temperature; typical values

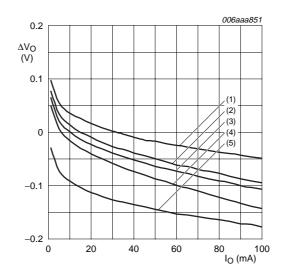


 $T_{amb} = 25 \, ^{\circ}C; I_{O} = 10 \, mA$

- (1) PVR100AD-B12V; $I_{ctrl} = 5 \text{ mA}$
- (2) PVR100AD-B3V3; I_{ctrl} = 6.5 mA
- (3) PVR100AD-B3V0; I_{ctrl} = 6.5 mA
- (4) PVR100AD-B2V5; $I_{ctrl} = 3.5 \text{ mA}$
- (5) PVR100AD-B5V0; I_{ctrl} = 10 mA

Fig 8. Voltage regulator: Output voltage variation as a function of input voltage; typical values

11 of 17



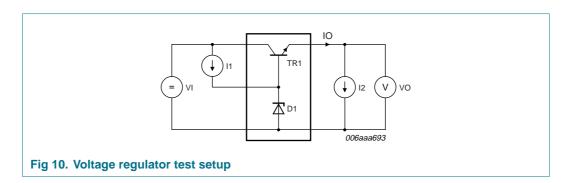
 T_{amb} = 25 °C; $V_I = V_{O(typ)} + 2 V$

- (1) PVR100AD-B12V; $I_{ctrl} = 5 \text{ mA}$
- (2) PVR100AD-B3V3; I_{ctrl} = 6.5 mA
- (3) PVR100AD-B3V0; $I_{ctrl} = 6.5 \text{ mA}$
- (4) PVR100AD-B2V5; I_{ctrl} = 3.5 mA
- (5) PVR100AD-B5V0; I_{ctrl} = 10 mA

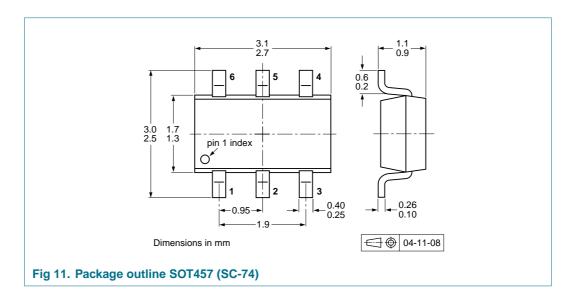
Product data sheet

Voltage regulator: Output voltage variation as a function of output current; typical values

8. Test information



9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

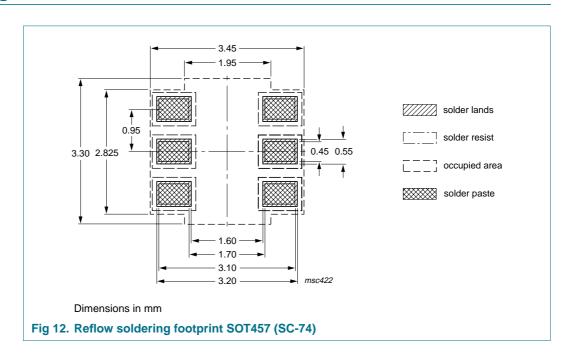
Type number	Package	Description		Packing	quantity
				3000	10000
PVR100AD-B2V5	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165
PVR100AD-B3V0	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165
PVR100AD-B3V3	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165
PVR100AD-B5V0	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165
PVR100AD-B12V	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	<u>[3]</u>	-125	-165

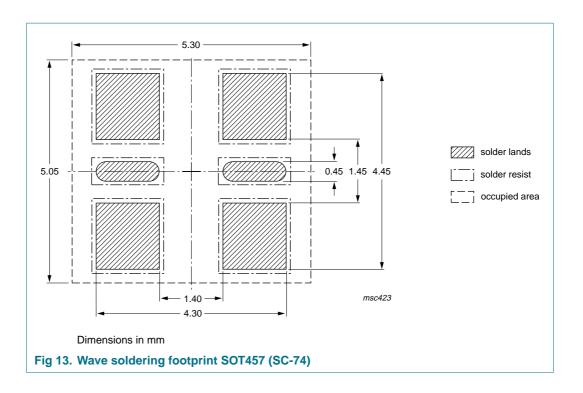
[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering





PVR100AD-B series

Voltage regulator series

12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PVR100AD-B_SER_1	20061031	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors

PVR100AD-B series

Voltage regulator series

15. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information 3
3	Ordering information
4	Marking 3
5	Limiting values 4
6	Thermal characteristics 5
7	Characteristics 6
8	Test information
9	Package outline 12
10	Packing information
11	Soldering 13
12	Revision history 15
13	Legal information 16
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks16
14	Contact information 16
15	Contents

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